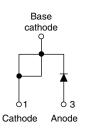


Vishay Semiconductors

Schottky Rectifier, 20 A





PRODUCT SUMMARY								
Package	TO-220AC							
I _{F(AV)}	20 A							
V _R	15 V							
V _F at I _F	See Electrical table							
I _{RM} max.	600 mA at 100 °C							
T _J max.	125 °C							
Diode variation	Single die							
E _{AS}	10 mJ							

FEATURES

- 125 °C T_J operation ($V_R < 5 V$)
- Optimized for OR-ing applications
- Ultra low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



RoHS

COMPLIANT

HALOGEN

FREE

- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The Schottky rectifier module has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	20	А						
V _{RRM}		15	V						
I _{FSM}	t _p = 5 μs sine	700	А						
V _F	19 A_{pk} , T_J = 125 °C (typical)	0.25	V						
TJ	Range	- 55 to 125	°C						

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-STPS20L15DPbF	VS-STPS20L15D-N3	UNITS				
Maximum DC reverse voltage	V _R	15	15	V				
Maximum working peak reverse voltage	V _{RWM}	15	10	v				

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONE	VALUES	UNITS					
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle, $T_C = 85$ °C, r	20	А					
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse Following any rated load condition and with rated		700) A				
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse		330	~				
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 6 mH	10	mJ					
Repetitive avalanche current	I _{AR}	Current decaying linearly to ze Frequency limited by T _J maxin	2	А					

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ELECTRICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CO	TYP.	MAX.	UNITS					
		19 A	T.I = 25 °C	-	0.41					
Forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	40 A	1j=25 0	-	0.52	v				
	V FM ()	19 A	T.I = 125 °C	0.25	0.33					
		40 A	- 1 _J = 125 C	0.37	0.50					
Reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	-	10	mA				
See fig. 2	IRM (**	T _J = 100 °C	$v_{\rm R}$ = nated $v_{\rm R}$	-	600	mA				
Threshold voltage	V _{F(TO)}	T - T movimum		0.1	182	V				
Forward slope resistance	r _t	$T_J = T_J$ maximum		7.6		mΩ				
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal rar	-	2000	pF					
Typical series inductance	L _S	Measured lead to lead 5 r	8	-	nH					
Maximum voltage rate of change	dV/dt	Rated V _R		10	000	V/µs				

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction temperature range	TJ		- 55 to 125	°C				
Maximum storage temperature range	T _{Stg}		- 55 to 150					
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	1.5					
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased (for TO-220)	0.50	°C/W				
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation (for D ² PAK)	40					
Approvimate weight			2	g				
Approximate weight			0.07	OZ.				
Mounting torque		Non-lubricated threads	6 (5)	kgf · cm				
Mounting torque maximum]	Non-Iubricated trifeads	12 (10)	(lbf ⋅ in)				
Marking device		Case style TO-220AC	STPS2	0L15D				

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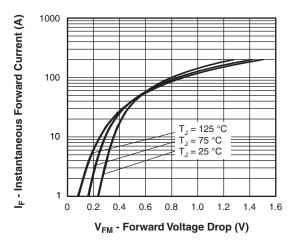


Fig. 1 - Maximum Forward Voltage Drop Characteristics

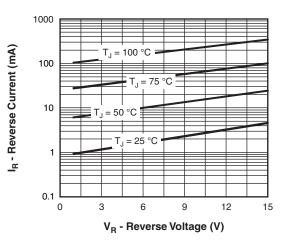


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

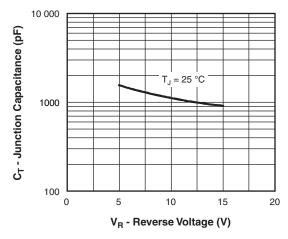
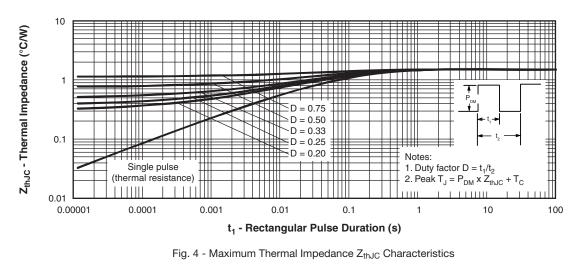


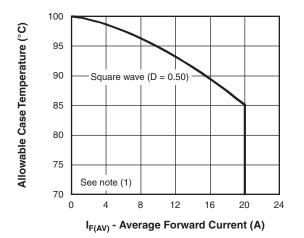
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

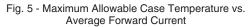


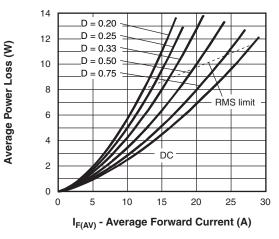
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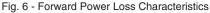


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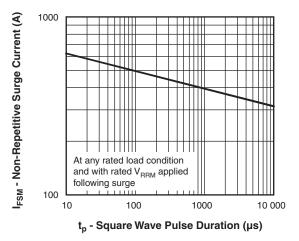


Fig. 7 - Maximum Non-Repetitive Surge Current

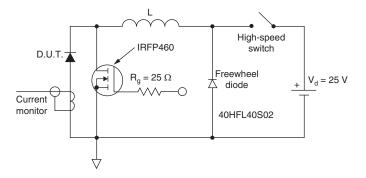


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}$ /D) (see fig. 6);

 Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; $I_R \text{ at } V_{R1}$ = 80 % rated V_R

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ORDERING INFORMATION TABLE

Device code	VS-	STPS	20	L	15	D	PbF				
	1	2	3	4	5	6	7				
	1 - 2 - 3 - 4 -	3 - Current rating (20 = 20 A)									
	5 - 6 - 7 -	· Volt	age ratii Essenti	ng (15 = al part n ntal digit	15 V) umber						
							complia				

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-STPS20L15DPbF	50	1000	Antistatic plastic tube					
VS-STPS20L15D-N3	50	1000	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS							
Dimensions		www.vishay.com/doc?95221					
Part marking information	TO-220AC PbF	www.vishay.com/doc?95224					
	TO-220AC -N3	www.vishay.com/doc?95068					
SPICE model		www.vishay.com/doc?95305					



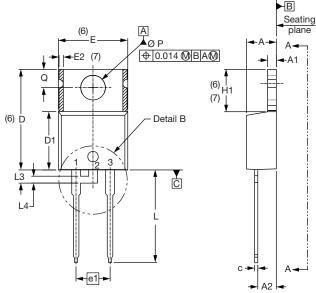
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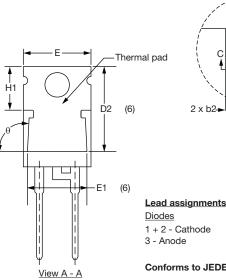
TO-220AC

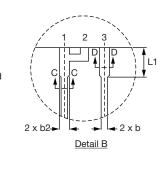
plane

A-

DIMENSIONS in millimeters and inches









Diodes 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220AC

⊕ 0.015 **()** BA()

SYMBOL	MILLIM	IETERS	INC	HES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183		E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055		E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115		е	2.41	2.67	0.095	0.105	
b	0.69	1.01	0.027	0.040		e1	4.88	5.28	0.192	0.208	
b1	0.38	0.97	0.015	0.038	4	H1	6.09	6.48	0.240	0.255	6, 7
b2	1.20	1.73	0.047	0.068		L	13.52	14.02	0.532	0.552	
b3	1.14	1.73	0.045	0.068	4	L1	3.32	3.82	0.131	0.150	2
с	0.36	0.61	0.014	0.024		L3	1.78	2.13	0.070	0.084	
c1	0.36	0.56	0.014	0.022	4	L4	0.76	1.27	0.030	0.050	2
D	14.85	15.25	0.585	0.600	3	ØΡ	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355		Q	2.60	3.00	0.102	0.118	
D2	11.68	12.88	0.460	0.507	6	θ	90° t	o 93°	90° t	o 93°	
E	10.11	10.51	0.398	0.414	3, 6						

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- ⁽⁵⁾ Controlling dimension: inches
- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2 and E1
- ⁽⁷⁾ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- ⁽⁸⁾ Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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